



M T B F

(EIAJ RCR-9102)

Model	DHS100B12
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	Reference
1	I C	Monolithic	2	0.0650	
2		Hybrid	0	0.0000	
3	Transistors		12	0.3069	
4	Diodes		26	0.4255	
5	LED·Optocouplers		2	0.1400	
6	Resistors		92	0.4380	
7	Capacitors		44	0.2516	
8	Transformer·Choke Coil		3	0.0230	
9	Connectors		63	0.1400	
10	Others		2	0.1130	
Total Failure Rate [10 ⁻⁶ /H]				1.9030	

M T B F	[H]	526,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—